

PT430/PT430F

Narrow Acceptance T-41-61
Phototransistor

■ Features

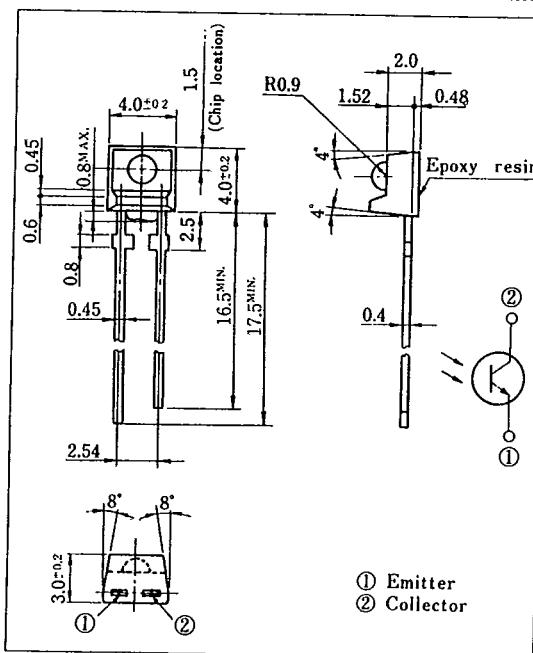
1. Narrow acceptance epoxy resin package
($\Delta\theta$: TYP. $\pm 13^\circ$)
 2. Visible light cut-off type : PT430F

■ Applications

1. VCRs, cassette tape recorders
 2. Optoelectronic switches, optoelectronic counters
 3. Automatic stroboscopes

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Rating	Unit
Collector-emitter voltage	V_{CEO}	35	V
Emitter-collector voltage	V_{ECO}	6	V
Collector current	I_C	20	mA
Collector power dissipation	P_C	75	mW
Operating temperature	T_{OPR}	-25 ~ +85	°C
Storage temperature	T_{STG}	-40 ~ +85	°C
* Soldering temperature	T_{SOL}	260	°C

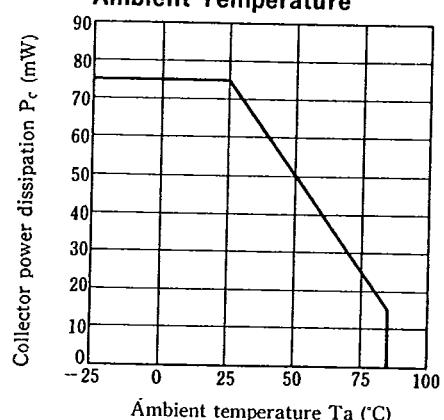
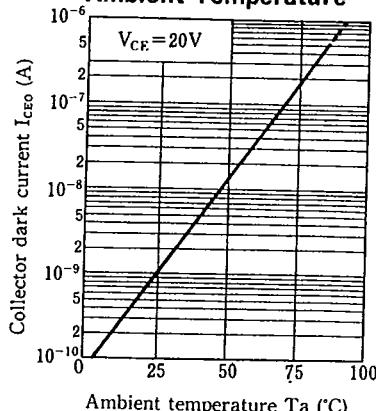
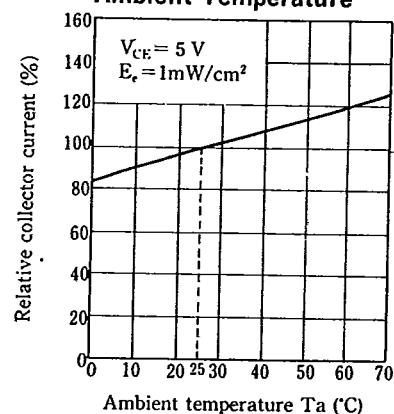
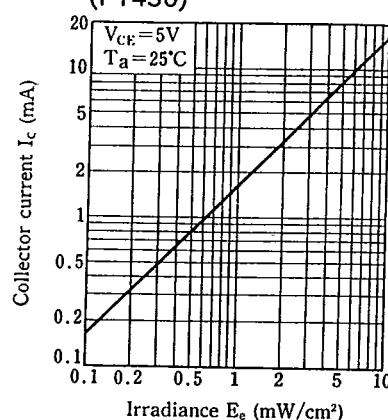
*1 For 3 seconds at the position of 2.5mm from the bottom face of resin package

■ Electro-optical Characteristics

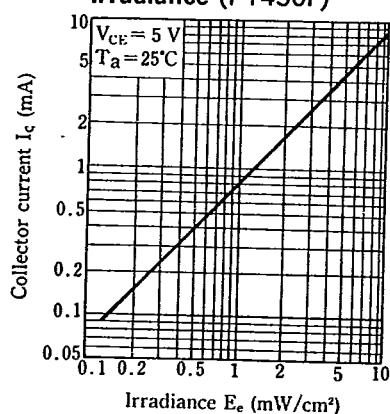
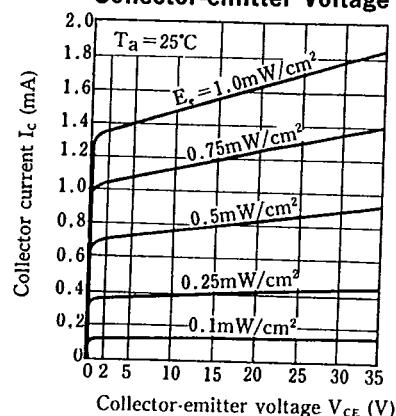
(Ta=25°C)

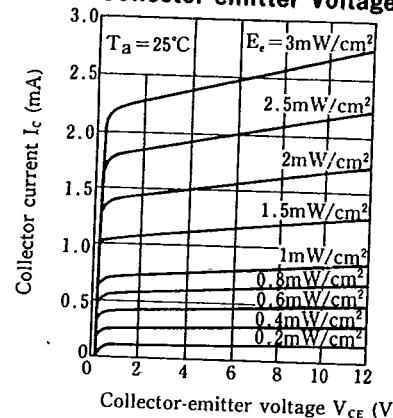
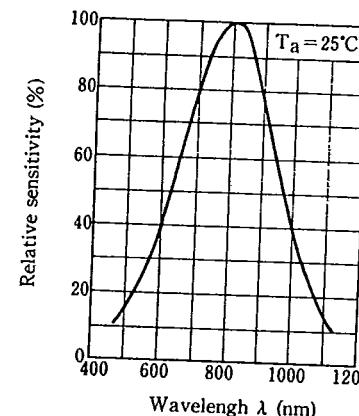
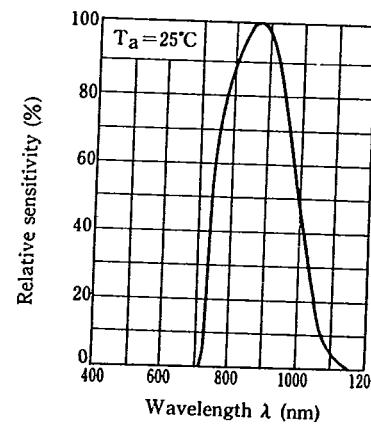
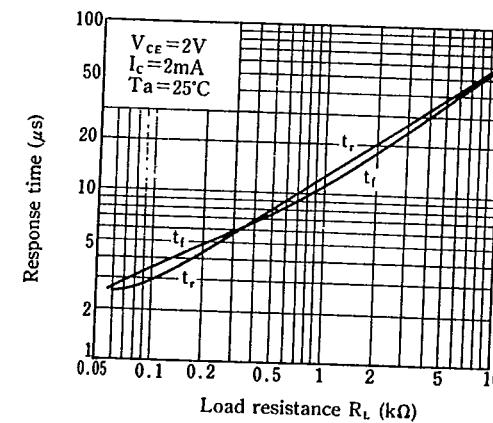
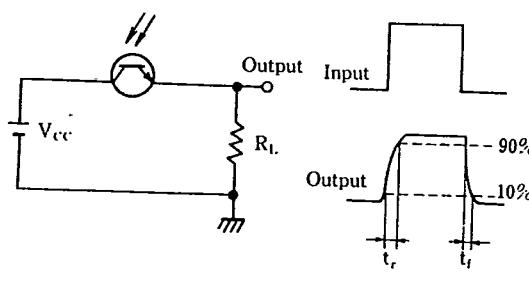
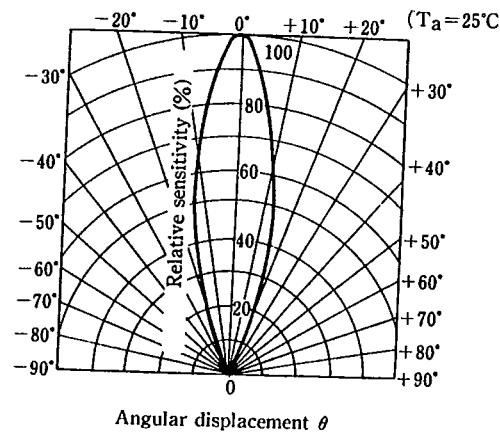
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Collector current	PT430	I_C	$V_{CE} = 5V$	0.4	1.7	6.0 mA
	PT430F		$E_e = 1mW/cm^2$	0.25	0.8	3.0 mA
Collector dark current	I_{CEO}	$V_{CE} = 20V, E_e = 0$	—	10^{-9}	10^{-7}	A
*2 Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 0.5mA, E_e = 10mW/cm^2$	—	0.1	0.4	V
Peak sensitivity wavelength	PT430	λ_p	—	800	—	nm
	PT430F		—	860	—	nm
Response time (Rise)	t_r	$V_{CE} = 2V, I_C = 2mA, R_L = 100\Omega$	—	3	—	μs
Response time (Fall)	t_f		—	3.5	—	μs

*2 E_e : Irradiance by CIE standard light source A (tungsten lamp)

Fig. 1 Collector Power Dissipation vs. Ambient Temperature**Fig. 2 Collector Dark Current vs. Ambient Temperature****Fig. 3 Relative Collector Current vs. Ambient Temperature****Fig. 4 Collector Current vs. Irradiance (PT430)**

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Fig. 5 Collector Current vs. Irradiance (PT430F)**Fig. 6 Collector Current vs. Collector-emitter Voltage (PT430)**

**Fig. 7 Collector Current vs.
Collector-emitter Voltage (PT430F)****Fig. 8 Spectral Sensitivity (PT430)****Fig. 9 Spectral Sensitivity (PT430F)****Fig. 10 Response Time vs. Load Resistance****Test Circuit for Response Time****Fig. 11 Sensitivity Diagram**

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Fig. 12 Collector-emitter Saturation Voltage vs. Irradiance (PT430)

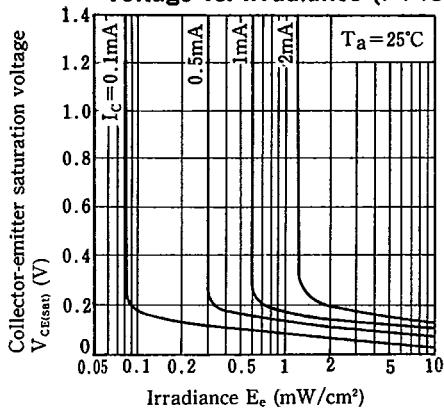


Fig. 13 Collector-emitter Saturation Voltage vs. Irradiance (PT430F)

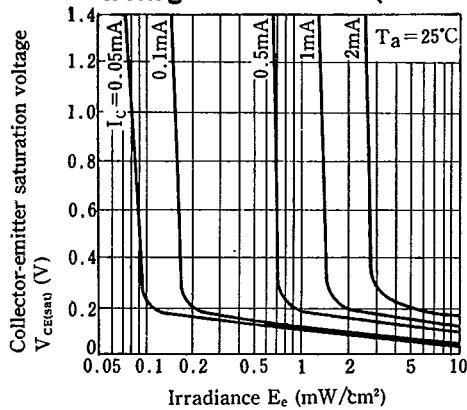


Fig. 14 Relative Output vs. Distance (Emitter : (GL430))

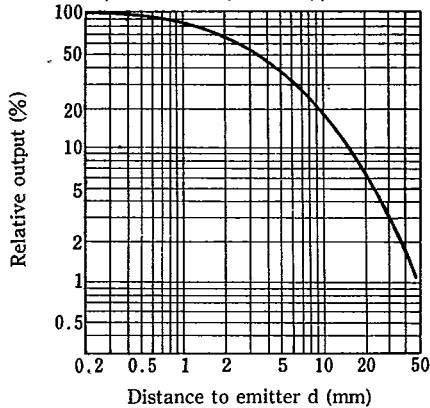


Fig. 15 Collector Current vs. Illuminace (Reference)

